

Ultrafast Soft Recovery Diode, 60 A FRED Pt®



PRODUCT SUMMARY					
Package	TO-247AD 2L				
I _{F(AV)}	60 A				
V_R	600 V				
V _F at I _F	1.05 V				
t _{rr} typ.	32 ns				
T _J max.	175 °C				
Diode variation	Single die				

FEATURES

- · Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

DESCRIPTION / APPLICATIONS

VS-EPU60... series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, welding, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current in DC	I _{F(AV)}	T _C = 116 °C	60	^			
Single pulse forward current	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms; half sine wave	600	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

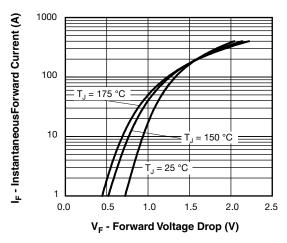
ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage		I _F = 60 A	-	1.2	1.5	V	
	V _F	I _F = 60 A, T _J = 125 °C	-	1.1	1.3	 	
		I _F = 60 A, T _J = 175 °C	-	1.05	1.2		
Reverse leakage current		V _R = V _R rated	-	0.2	30		
	I _R	$T_J = 150 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	200	μΑ	
Junction capacitance	C _T	V _R = 600 V	-	38	-	pF	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
		I _F = 1 A, dI _F /dt = 200 A/μs, V _R = 30 V		-	32	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	110	-	ns	
		T _J = 125 °C	I _F = 60 A dI _F /dt = 200 A/μs V _R = 200 V	-	200	-		
Peak recovery current	I _{RRM}	T _J = 25 °C		-	10	-	Α	
		T _J = 125 °C		-	19	-	_ ^	
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	530	-	nC	
		T _J = 125 °C		-	1900	-	IIC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	0.65		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70	°C/W	
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Woight			-	6	-	g	
Weight			-	0.21	-	oz.	
Mounting torque			6 (5)	-	1.2 (10)	kgf. cm (lbf · in)	
Marking device		Case style TO-247AD 2L		EPU6	6006L		





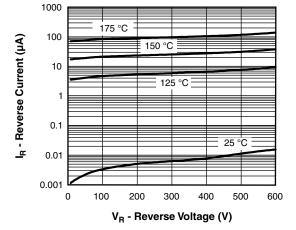


Fig. 1 - Typical Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

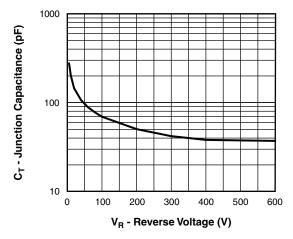


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

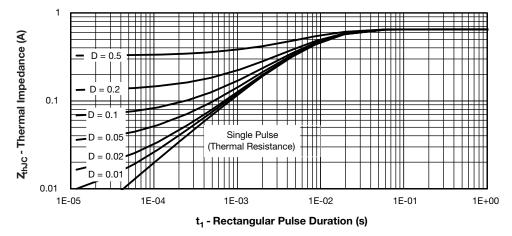


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



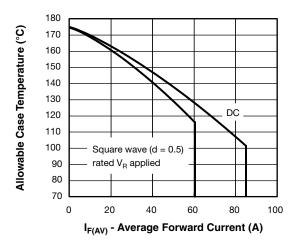


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

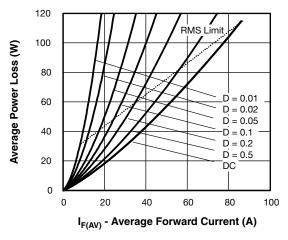


Fig. 6 - Forward Power Loss Characteristics

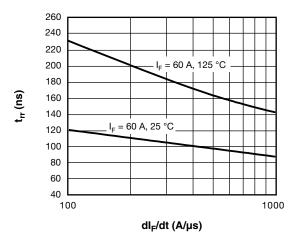


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

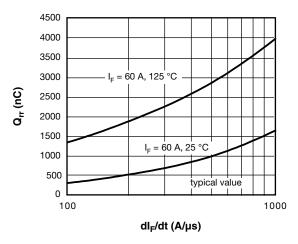
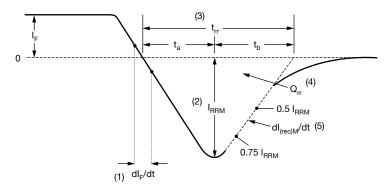


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{B1} \times I_B (1 - D)$; I_B at $V_{B1} = 80 \%$ rated V_B



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_{r}$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{RRM}$

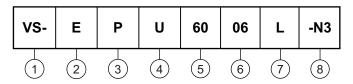
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) dI_{(rec)M}/dt - peak rate of change of current during t_h portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Circuit configuration:
 - E = single diode 2 pins
- **3** P = TO-247
- 4 U = ultrafast recovery time
- 5 Current code (60 = 60 A)
- 6 Voltage code (06 = 600 V)
- 7 L = long lead
- 8 Environmental digit:

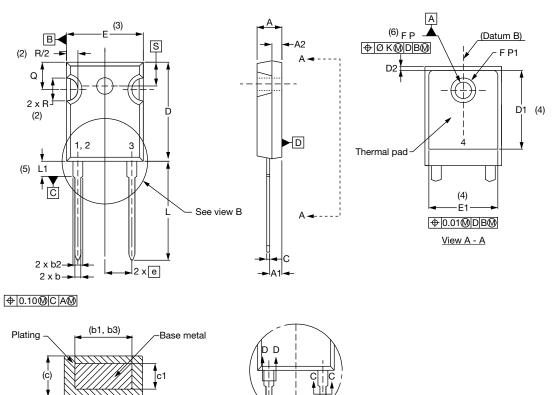
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-EPU6006L-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536		
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648		

TO-247AD 2L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	MILLIMETERS		INCHES	
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

Section C - C, D - D

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØK	0.2	0.254		10	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	
	•		•	•	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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